



MM74HC4060 14 Stage Binary Counter

General Description

The MM74HC4060 is a high speed binary ripple carry counter. These counters are implemented utilizing advanced silicon-gate CMOS technology to achieve speed performance similar to LS-TTL logic while retaining the low power and high noise immunity of CMOS.

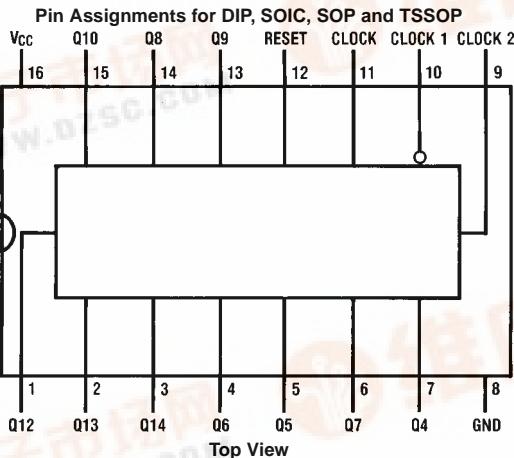
The MM74HC4060 is a 14-stage counter, which device increments on the falling edge (negative transition) of the input clock, and all their outputs are reset to a low level by applying a logical high on their reset input. The MM74HC4060 also has two additional inputs to enable easy connection of either an RC or crystal oscillator.

Ordering Code:

Order Number	Package Number	Package Description
MM74HC4060M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4060SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4060MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4060N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

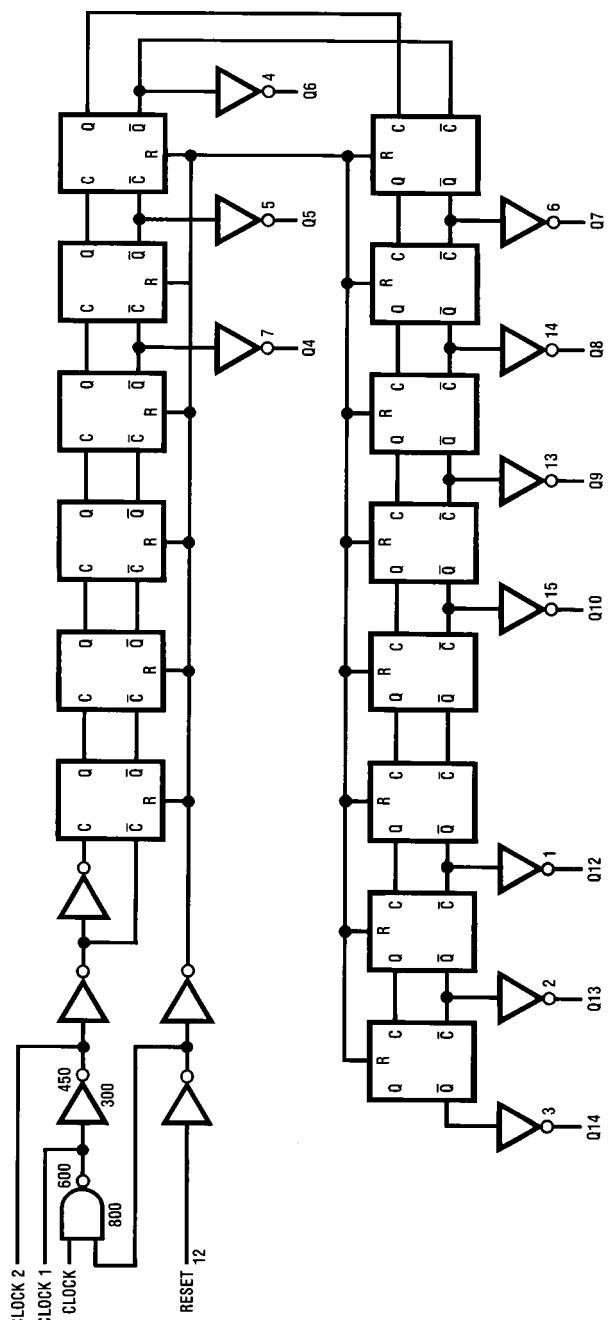
Connection Diagram



August 1984
Revised February 1999

MM74HC4060 14 Stage Binary Counter

Logic Diagram



Absolute Maximum Ratings (Note 1)				Recommended Operating Conditions			
(Note 2)							
Supply Voltage (V_{CC})	-0.5 to +7.0V			Supply Voltage (V_{CC})	2	6	V
DC Input Voltage (V_{IN})	-1.5 to V_{CC} +1.5V			DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
DC Output Voltage (V_{OUT})	-0.5 to V_{CC} +0.5V			Operating Temperature Range (T_A)	-40	+85	°C
Clamp Diode Current (I_{CD})	±20 mA			Input Rise or Fall Times (t_r, t_f)	$V_{CC} = 2.0V$	1000	ns
DC Output Current, per pin (I_{OUT})	±25 mA			$V_{CC} = 4.5V$		500	ns
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA			$V_{CC} = 6.0V$		400	ns
Storage Temperature Range (T_{STG})	-65°C to +150°C			Note 1: Maximum Ratings are those values beyond which damage to the device may occur.			
Power Dissipation (P_D) (Note 3)	600 mW			Note 2: Unless otherwise specified all voltages are referenced to ground.			
S.O. Package only	500 mW			Note 3: Power Dissipation temperature derating: plastic "N" package: -12 mW/°C from 65°C to 85°C.			
Lead Temperature (T_L) (Soldering 10 seconds)	260°C						
DC Electrical Characteristics (Note 4)							
Symbol	Parameter	Conditions	V_{CC}	$T_A = 25^\circ C$		$T_A = -40 \text{ to } 85^\circ C$	$T_A = -55 \text{ to } 125^\circ C$
				Typ		Guaranteed Limits	
V_{IH}	Minimum HIGH Level Voltage (Not Applicable to Pins 9 & 10)		2.0V		1.5	1.5	1.5
			4.5V		3.15	3.15	3.15
			6.0V		4.2	4.2	4.2
V_{IL}	Maximum LOW Level Input Voltage (Not Applicable to Pins 9 & 10)		2.0V		0.5	0.5	0.5
			4.5V		1.35	1.35	1.35
			6.0V		1.8	1.8	1.8
V_{OH}	Minimum HIGH Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 20 \mu A$	2.0V	2.0	1.9	1.9	1.9
			4.5V	4.5	4.4	4.4	4.4
			6.0V	6.0	5.9	5.9	5.9
	Except Pins 9 & 10	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 4.0 \text{ mA}$ $ I_{OUT} \leq 5.2 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7
			6.0V	5.7	5.48	5.34	5.2
	Pins 9 & 10	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} = 0.4 \text{ mA}$ $ I_{OUT} = 0.52 \text{ mA}$			3.98	3.84	3.7
V_{OL}	Maximum LOW Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 20 \mu A$	2.0V	0	0.1	0.1	0.1
			4.5V	0	0.1	0.1	0.1
			6.0V	0	0.1	0.1	0.1
	Except Pins 9 & 10	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 4.0 \text{ mA}$ $ I_{OUT} \leq 5.2 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4
			6.0V	0.2	0.26	0.33	0.4
	Pins 9 & 10	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} = 0.4 \text{ mA}$ $ I_{OUT} = 0.52 \text{ mA}$			0.26	0.33	0.4
I_{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0
I_{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \mu A$	6.0V		8.0	80	160
Note 4: For a power supply of $5V \pm 10\%$ the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.							

AC Electrical Characteristics

$V_{CC} = 5V$, $T_A = 25^\circ C$, $C_L = 15 \text{ pF}$, $t_r = t_f = 6 \text{ ns}$

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Clock Frequency			30	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay to Q_4	(Note 5)	40	20	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay to any Q		16	40	ns
t_{REM}	Minimum Reset Removal Time		10	20	ns
t_W	Minimum Pulse Width		10	16	ns

AC Electrical Characteristics

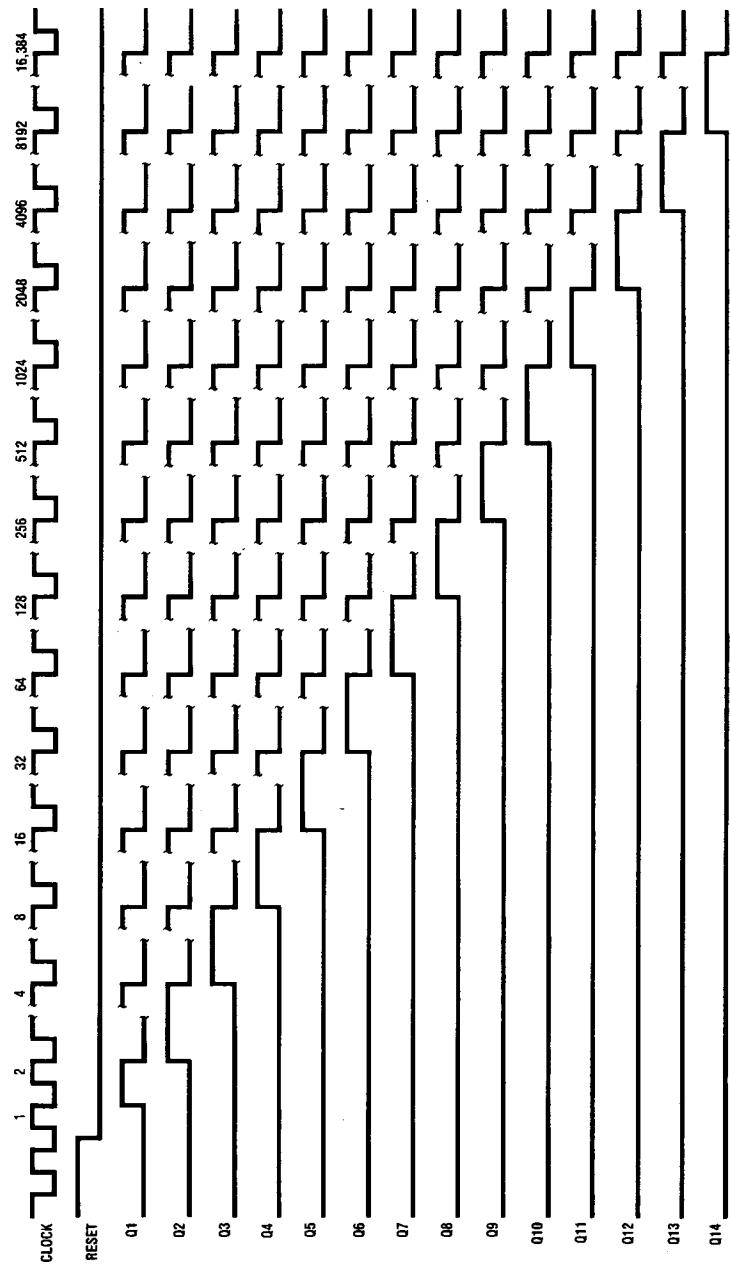
$V_{CC} = 2.0 \text{ V to } 6.0 \text{ V}$, $C_L = 50 \text{ pF}$, $t_r = t_f = 6 \text{ ns}$ (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25^\circ C$		$T_A = -40 \text{ to } 85^\circ C$	$T_A = -55 \text{ to } 125^\circ C$	Units
				Typ	Guaranteed Limits			
f_{MAX}	Maximum Operating Frequency		2.0V	6	5	4	20	MHz
			4.5V	30	24	20	24	MHz
			6.0V	35	28	24	24	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock to Q_4		2.0V	120	380	475	171	ns
			4.5V	42	76	95	114	ns
			6.0V	35	65	81	97	ns
t_{PHL}	Maximum Propagation Delay Reset to any Q		2.0V	72	240	302	358	ns
			4.5V	24	48	60	72	ns
			6.0V	20	41	51	61	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay Between Stages Q_n to Q_{n+1}		2.0V	125	156	156	188	ns
			4.5V	25	31	31	38	ns
			6.0V	21	26	26	31	ns
t_{REM}	Minimum Reset Removal Time		2.0V	100	125	125	150	ns
			4.5V	20	25	25	30	ns
			6.0V	17	21	21	25	ns
t_W	Minimum Pulse Width		2.0V	80	100	100	120	ns
			4.5V	16	20	20	24	ns
			6.0V	14	17	17	20	ns
t_r, t_f	Maximum Input Rise and Fall Time		2.0V	1000	1000	1000	1000	ns
			4.5V	500	500	500	500	ns
			6.0V	400	400	400	400	ns
t_{THL}, t_{TLH}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	10	15	19	22	ns
			6.0V	9	13	16	19	ns
C_{PD}	Power Dissipation Capacitance (Note 6)	(per package)		55				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: Typical Propagation delay time to any output can be calculated using: $t_p = 17 + 12(N-1) \text{ ns}$; where N is the number of the output, Q_W , at $V_{CC} = 5V$.

Note 6: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

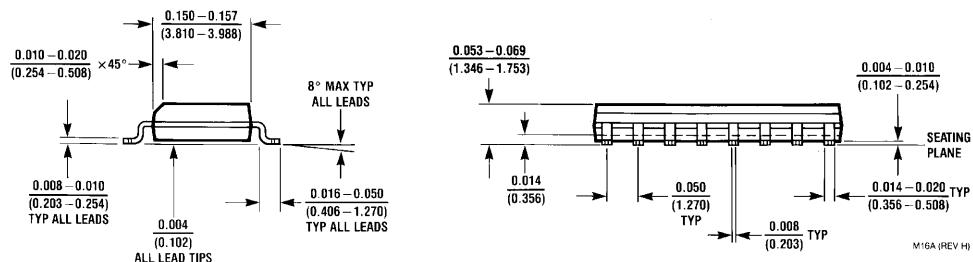
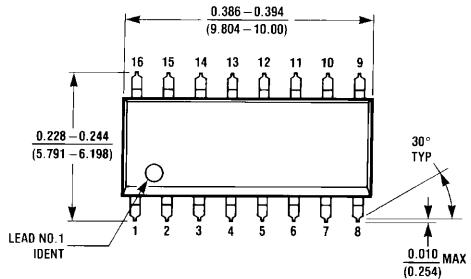
Timing Diagram



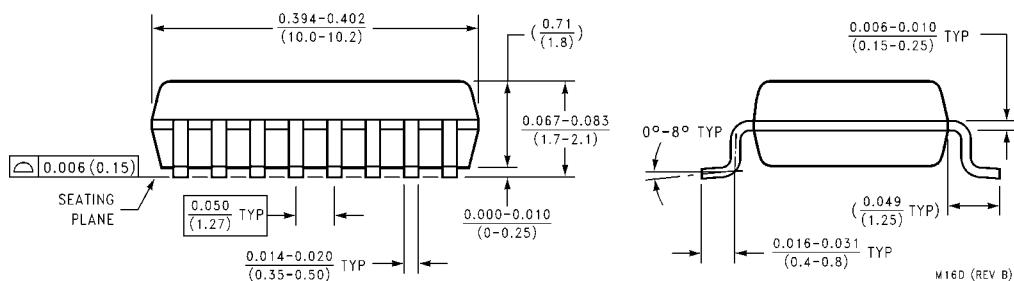
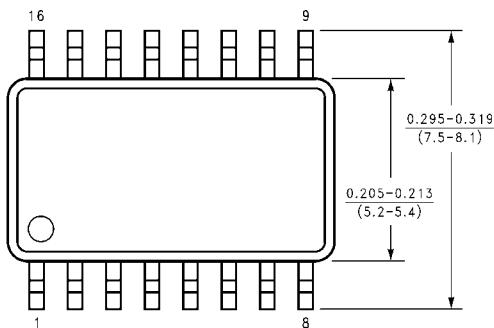
MM74HC4060

Physical Dimensions

inches (millimeters) unless otherwise noted



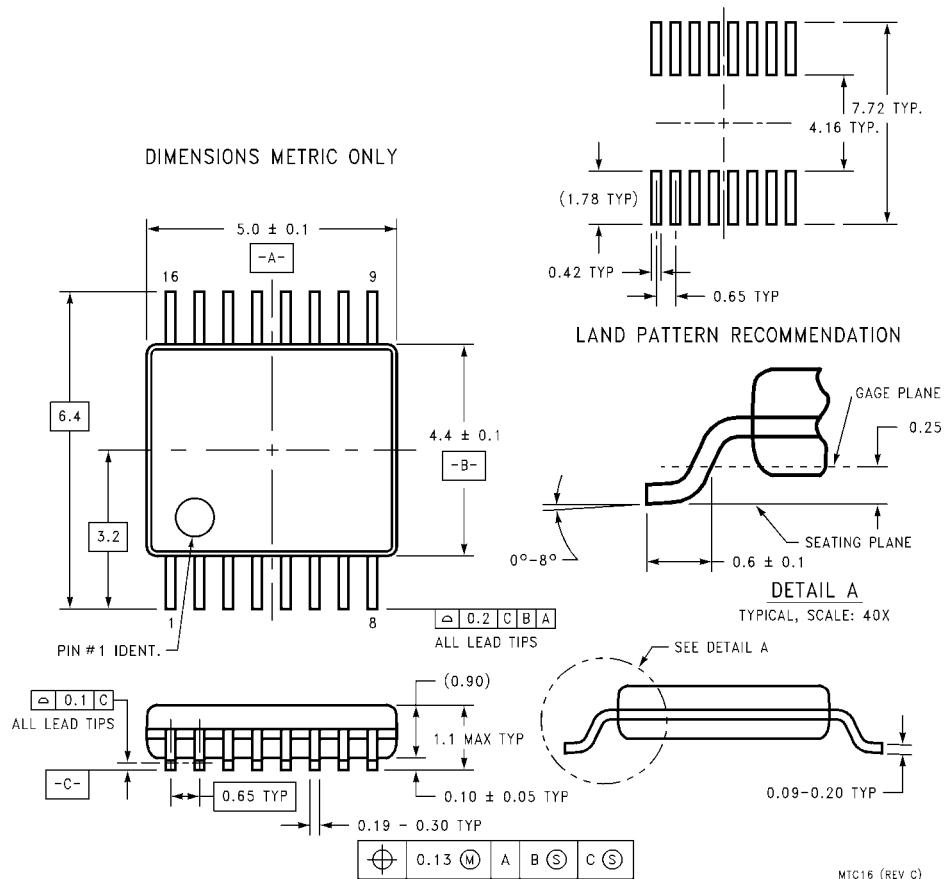
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions

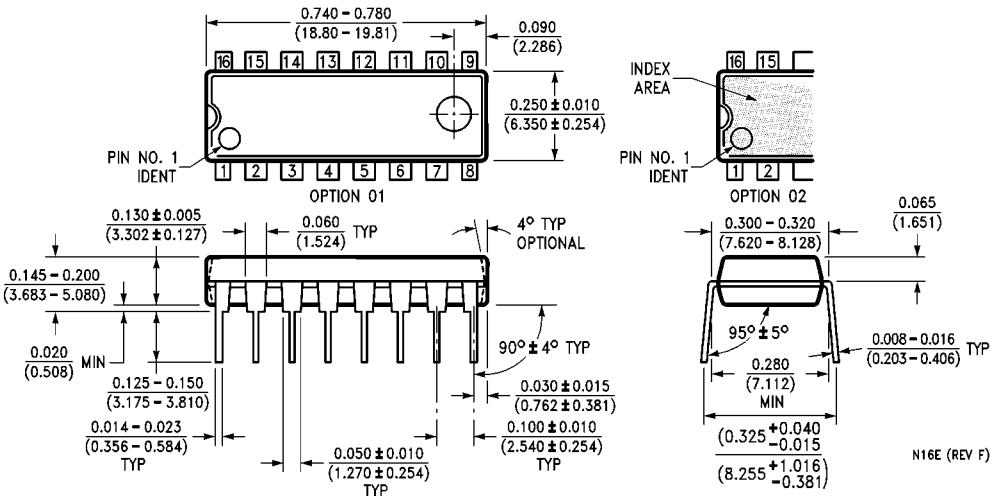
inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions

inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

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